

Afrah Bardaoui

List of Publications by Year in descending order

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33
papers

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758635

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34
times ranked

426
citing authors

#	ARTICLE	IF	CITATIONS
1	Structural, morphological and electrical characteristics of electrodeposited Cu ₂ O: Effect of deposition time. <i>Applied Surface Science</i> , 2016, 366, 383-388.	3.1	54
2	Correlation between optical and structural properties of copper oxide electrodeposited on ITO glass. <i>Journal of Alloys and Compounds</i> , 2014, 611, 142-148.	2.8	26
3	Design of silicon-based two-dimensional photonic integrated circuits: XOR gate. <i>IET Optoelectronics</i> , 2013, 7, 25-29.	1.8	23
4	Synthesis and characterization of ZnO/Cu ₂ O core-shell nanowires grown by two-step electrodeposition method. <i>Applied Surface Science</i> , 2015, 343, 148-152.	3.1	23
5	Morphological, structural and ellipsometric investigations of Cr doped TiO ₂ thin films prepared by sol-gel and spin coating. <i>Ceramics International</i> , 2016, 42, 10599-10607.	2.3	23
6	Characterization of Ag-doped ZnO thin films by spray pyrolysis and its using in enhanced photoelectrochemical performances. <i>Inorganic Chemistry Communication</i> , 2020, 119, 108114.	1.8	23
7	Correlation between Titanium foil substrate purity and TiO ₂ NTs; physical and electrochemical properties for enhanced photoelectrochemical applications. <i>International Journal of Hydrogen Energy</i> , 2016, 41, 6230-6239.	3.8	19
8	Physical properties of graphene oxide GO-doped ZnO thin films for optoelectronic application. <i>Applied Physics A: Materials Science and Processing</i> , 2021, 127, 1.	1.1	17
9	Photoluminescence studies of 2DEG confinement in InAs ultrathin layer introduced in GaAs/AlGaAs structure. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2010, 42, 2134-2138.	1.3	14
10	Effects of gamma irradiation on photoluminescence and activation energy of epoxy resin. <i>Superlattices and Microstructures</i> , 2013, 55, 191-197.	1.4	14
11	Correlation between physical properties and growth mechanism of In ₂ S ₃ thin films fabricated by electrodeposition technique with different deposition times. <i>EPJ Applied Physics</i> , 2015, 72, 10302.	0.3	14
12	Metal deposition on porous silicon by immersion plating to improve photoluminescence properties. <i>Journal of Luminescence</i> , 2016, 173, 257-262.	1.5	14
13	Structural, optical and electrical properties of the Zn doped MoO ₃ deposited on porous silicon. <i>Sensors and Actuators A: Physical</i> , 2019, 297, 111537.	2.0	13
14	Annealing temperature investigation on electrodeposited Cu ₂ O properties. <i>Phase Transitions</i> , 2020, 93, 1089-1099.	0.6	10
15	Photorefectance study of InAs ultrathin layer embedded in Si-delta-doped GaAs/AlGaAs quantum wells. <i>Journal of Luminescence</i> , 2011, 131, 1007-1012.	1.5	9
16	Effect of rapid thermal treatment on optical properties of porous silicon surface doped lithium. <i>Journal of Luminescence</i> , 2015, 160, 176-180.	1.5	8
17	An easy-to achieve approach for the fabrication of CdS QDs sensitized TiO ₂ nanotubes and their enhanced photoelectrochemical performance. <i>Journal of Photochemistry and Photobiology A: Chemistry</i> , 2017, 332, 337-344.	2.0	8
18	Study of the structural, electronic, magnetic and magnetocaloric properties of La _{0.5} Ca _{0.5} Mn _{0.9} V _{0.1} O ₃ sample: first-principles calculation (DFT-MFT). <i>RSC Advances</i> , 2021, 11, 37896-37903.	1.7	8

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19	Effect of rapid oxidation on optical and electrical properties of silicon nanowires obtained by chemical etching. EPJ Applied Physics, 2012, 58, 20103.	0.3	7
20	Photoluminescence study of nitrogen effects on confined states in GaAs _{1-x} N _x GaAs quantum wells. EPJ Applied Physics, 2009, 47, 30302.	0.3	6
21	Hydrothermal synthesis of CuMn ₂ O ₄ spinel-coated stainless steel mesh as a supercapacitor electrode. Journal of Materials Science: Materials in Electronics, 2022, 33, 12726-12733.	1.1	5
22	Hydrothermal synthesis of Ag-doped ZnO/sepiolite nanostructured material for enhanced photocatalytic activity. Environmental Science and Pollution Research, 2022, 29, 67159-67169.	2.7	5
23	Ellipsometric investigation of porous silicon layers for the design of a DBR. EPJ Applied Physics, 2008, 43, 87-91.	0.3	4
24	Study of n+ type porous GaAs by photoluminescence spectroscopy: Effect of the etching time on the deep levels. Applied Surface Science, 2010, 256, 5946-5951.	3.1	4
25	Ellipsometric investigations of Fe ³⁺ -doped polyvinyl alcohol films. Colloid and Polymer Science, 2013, 291, 2705-2709.	1.0	4
26	Relationship between microstructure and optical properties of a novel perovskite C ₁₂ PbI ₄ embedded in matrix of porous alumina. Superlattices and Microstructures, 2013, 53, 204-212.	1.4	4
27	Influence of single-walled carbon nanotubes functionalization in photocatalytic performance of pyramidal porous silicon: Experimental evidence. Materials Letters, 2020, 266, 127473.	1.3	3
28	Porous silicon optical microcavity for chemical sensing application using tris-(8-hydroxyquinoline) aluminum (Alq ₃). EPJ Applied Physics, 2010, 51, 30701.	0.3	2
29	Spectroscopic ellipsometry investigation and morphological characterization of electrodeposited Cu ₂ O thin films: annealing effect. Phase Transitions, 2020, 93, 1171-1182.	0.6	2
30	Correlation of atomic force microscopy and photoluminescence analysis of GaAs nanocrystallites elaborated by electrochemical etching of n ⁺ type GaAs. EPJ Applied Physics, 2010, 51, 20501.	0.3	1
31	Design and optimization of an OR gate all optical circuit based on silicon photonic crystals. EPJ Applied Physics, 2011, 56, 30501.	0.3	1
32	Photoluminescence study of the GaAs barrier effect on GaAs/GaInAs/GaAs quantum wells. , 2007, , .		0
33	Optical Constants of As-grown and RTA GaAs _{1-x} N _x Layers Analysed by Spectroscopic Ellipsometry. , 2007, , .		0